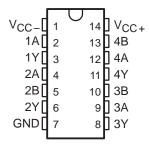
- Bi-MOS Technology With TTL and CMOS Compatibility
- Meets or Exceeds the Requirements of ANSI EIA/TIA-232-E and ITU Recommendation V.28
- Very Low Quiescent Current . . . 95 μ A Typ $V_{CC\pm}$ = \pm 12 V
- Current-Limited Outputs . . . 10 mA Typ
- CMOS-and TTL-Compatible Inputs
- On-Chip Slew Rate Limited to 30 V/μs max
- Flexible Supply Voltage Range
- Characterized at V_{CC±} of ±4.5 V and ±15 V
- Functionally Interchangeable With Texas Instruments SN75188, Motorola MC1488, and National Semiconductor DS14C88

D, DB[†], OR N PACKAGE (TOP VIEW)



† The DB package is only available left-end taped and reeled, i.e., order device SN75C188DBLE.

description

The SN75C188 is a monolithic, low-power, quadruple line driver that interfaces data terminal equipment with data communications equipment. This device is designed to conform to ANSI Standard EIA/TIA-232-E.

An external diode in series with each supply-voltage terminal is needed to protect the SN75C188 under certain fault conditions to comply with EIA/TIA-232-E.

The SN75C188 is characterized for operation from 0°C to 70°C.

Function Tables

DRIVER 1					
В Ү					
Н	L				
L	Н				

DRIVERS 2 - 4

Α	В	Υ
Н	Н	L
L	X	Н
Χ	L	Н

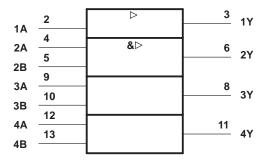
H = high level, L = low level, X = don't care



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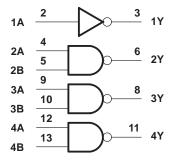


logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

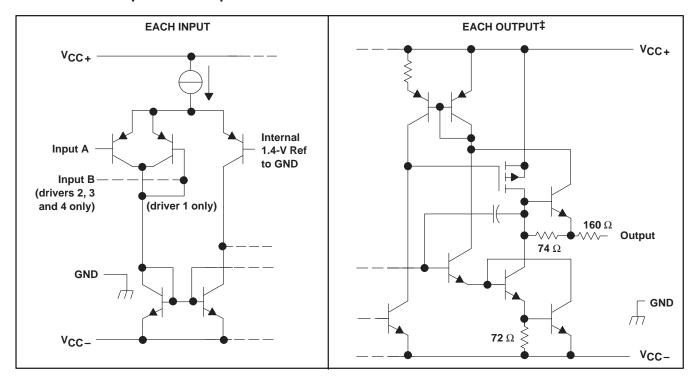
logic diagram (positive logic)



positive logic

 $Y = \overline{A} (driver 1)$ $Y = \overline{AB} \text{ or } \overline{A} + \overline{B} (drivers 2 \text{ through 4})$

schematics of inputs and outputs



[‡] All resistor values shown are nominal.



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC+} (see Note 1)	15 V
Supply voltage, V _{CC} (see Note 1)	
Input voltage range, V _I	V _{CC} - to V _{CC+}
Output voltage range, VO	V_{CC-} –6 V to V_{CC+} +6 V
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{stq}	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to the network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING
D	950 mW	7.6 mW/°C	608 mW
DB	525 mW	4.2 mW/°C	336 mW
N	1150 mW	9.2 mW/°C	736 mW

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC+}	4.5	12	15	V
Supply voltage, V _{CC} _	-4.5	-12	-15	V
Input voltage, V _I	V _{CC} -+2		VCC+	V
High-level Input voltage, VIH	2			V
Low-level Input voltage, V _{IL}			0.8	V
Operating free-air temperature, T _A	0		70	°C



electrical characteristics over operating free-air temperature range, $V_{CC+} = 12 \text{ V}$, $V_{CC-} = -12 \text{ V}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP [†]	MAX	UNIT	
V _{ОН}	High-level output voltage	1		V _{CC+} = 5 V, V _{CC-} = -5 V	4			V
VOH	r ngr-lever output voltage	VIL = 0.0 V,	N_ = 3 K22	V _{CC+} = 12 V, V _{CC-} = -12 V	10			V
V _{OL}	Low-level output voltage	V _{IH} = 2 V,	$R_1 = 3 k\Omega$	V _{CC+} = 5 V, V _{CC-} = -5 V			-4	٧
VOL	(see Note 2)	VIH - 2 v,	N_ = 3 N22	V _{CC+} = 12 V, V _{CC-} = -12 V			-10	v
lН	High-level input current	V _I = 5 V					10	μΑ
IIL	Low-level input current	V _I = 0					-10	μΑ
IOS(H)	High-level short-circuit output current‡	$V_I = 0.8 \text{ V}, \qquad V_O = 0 \text{ or } V_{CC-}$		-5.5	-10	-19.5	mA	
IOS(L)	Low-level short-circuit output current‡	$V_1 = 2 V$, $V_0 = 0 \text{ or } V_{CC+}$		5.5	10	19.5	mA	
rO	Output resistance, power off	$V_{CC+} = 0$,	V _{CC} -= 0,	$V_I = -2 V \text{ to } 2 V$	300			Ω
laa	Supply current from V _{CC+}	V _{CC+} = 5 V, No load	V _{CC} -=-5 V,	All inputs at 2 V or 0.8 V		90	160	μA
ICC+	Supply carrent from vCC+	V _{CC+} = 12 V, No load	V _{CC} -=-12 V,	All inputs at 2 V or 0.8 V		95	160	μΑ
		V _{CC+} = 5 V, No load	V _{CC} -=-5 V,	All inputs at 2 V or 0.8 V		-90	-160	
Icc-	Supply current from V _{CC} _	V _{CC+} = 12 V, No load	V _{CC} -=-12	All inputs at 2 V or 0.8 V		-95	-160	μА

[†] All typical values are at $T_A = 25$ °C.

NOTE 2: The algebraic convention, in which the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only; e.g., if $-4\ V$ is a maximum, the typical value is a more negative voltage.

switching characteristics, V_{CC+} = 12 V, V_{CC-} = -12 V, T_A = 25°C

	PARAMETER	TEST CONDITIONS			TYP	MAX	UNIT
tPLH	Propagation delay time, low- to high-level output§	$R_L = 3 k\Omega$,	C _L = 15 pF,			3	μs
tPHL	Propagation delay time, high- to low-level output§	See Figure 1				3.5	μs
tTLH	Transition time, low- to high-level output			0.53		3.2	μs
^t THL	Transition time, high- to low-level output			0.53		3.2	μs
tTLH	Transition time, low- to high-level output#	$R_L = 3 k\Omega$ to $7 k\Omega$,	C _L = 2500 pF,		1.5		μs
^t THL	Transition time, high- to low-level output#	See Figure 1			1.5		μs
SR	Output slew rate§	$R_L = 3 k\Omega \text{ to } 7 k\Omega$	C _L = 15 pF	6	15	30	V/μs

[§] Measured at the 50% level

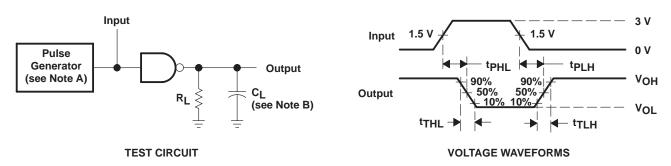


[‡] Not more than one output should be shorted at a time.

[¶] Measured between the 10% and 90% points on the output waveform

[#] Measured between the 3-V and -3-V points on the output waveform (EIA/TIA-232-E conditions), all unused inputs tied either high or low

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The pulse generator has the following characteristics: t_W = 25 μ s, PRR = 20 kHZ, Z_O = 50 Ω , t_f = t_f \leq 50 ns.

B. C_L includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

VOLTAGE TRANSFER CHARACTERISTICS 15 $V_{CC\pm} = \pm 15 V$ V_{CC±} = ±12 V 12 $V_{CC\pm} = \pm 9 V$ 9 V_O - Output Voltage - V $V_{CC\pm} = \pm 5 V$ 6 3 0 $V_{CC\pm} = \pm 5 V$ -3-6 $V_{CC\pm} = \pm 9 V$ $V_{CC\pm} = \pm 12 V$ -9 $R_L = 3 k\Omega$ $V_{CC\pm}$ = ± 5 V -12T_A = 25°C 0.2 0.4 0.6 0.8 1 1.2 1.4 1.6 1.8 0 V_I - Input Voltage - V

Figure 2

SHORT-CIRCUIT OUTPUT CURRENT FREE-AIR TEMPERATURE 15 $V_{CC\pm} = \pm 12 V$ IOS - Short-Circuit Output Current - mA 10 I_{OS(L)} V_I = 2 V 5 $V_O = 0$ or V_{CC+} 0 -5 $I_{OS(H)}$ $V_{I} = 0.8 V$ $V_O = 0$ or V_{CC} -10-1520 60 80 100 120 T_A - Free-Air Temperature - °C

Figure 4

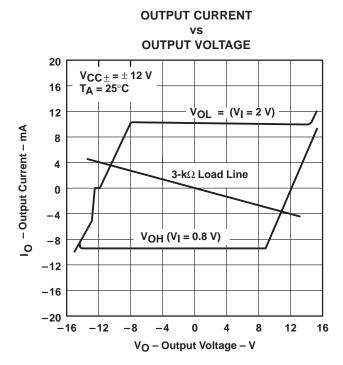
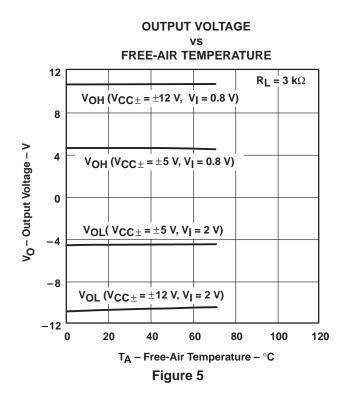
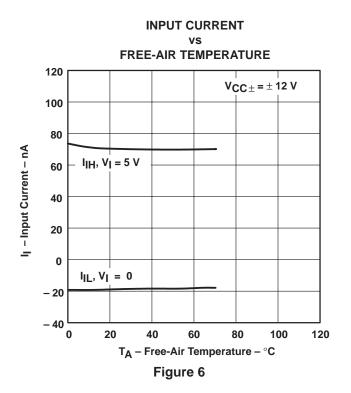


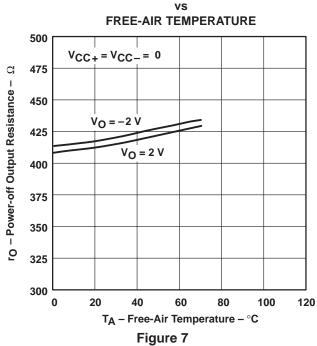
Figure 3

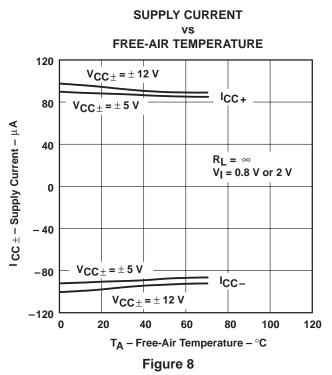


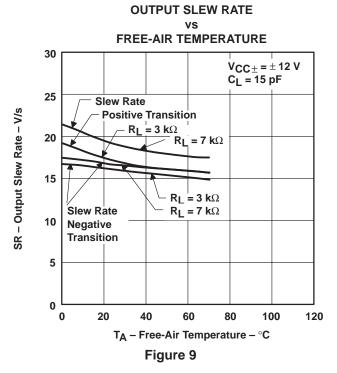
POWER-OFF OUTPUT RESISTANCE

TYPICAL CHARACTERISTICS

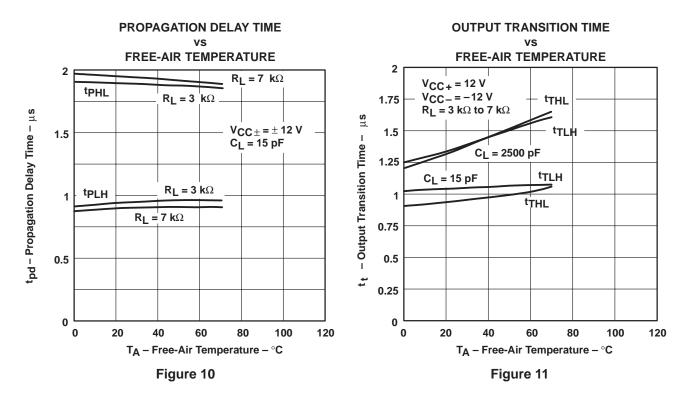








TYPICAL CHARACTERISTICS



APPLICATION INFORMATION

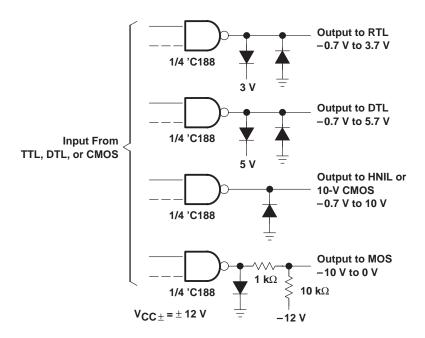
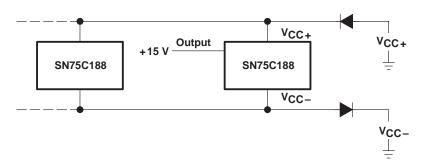


Figure 12. Logic Translator Applications



APPLICATION INFORMATION



NOTE A: External diodes placed in series with the V_{CC-} and V_{CC-} leads protect the SN75C188 in the fault condition where the device outputs are shorted to \pm 15 V and the power supplies are at low voltage and provide low-impedance paths to GND.

Figure 13. Power Supply Protection to Meet Power-Off Fault Conditions of Standard EIA/TIA-232-E



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SN75C188, QUADRUPLE LOW-POWER LINE DRIVER

Device Status: Active

- > Description
- > Features
- > Datasheets
- > Pricing/Samples/Availability
- > Application Notes
- > Related Documents
- > Development Tools
- > Applications

Parameter Name	SN75C188
Drivers Per Package	4
Driver tpd (ns)	3500
Driver (RL) (Ohms)	300
Supply Voltage(s) (V)	+- 12
ICC (max) (mA)	0.16
Footprint	MC1488

Description

The SN75C188 is a monolithic, low-power, quadruple line driver that interfaces data terminal equipment with data communications equipment. This device is designed to conform to ANSI Standard EIA/TIA-232-E.

An external diode in series with each supply-voltage terminal is needed to protect the SN75C188 under certain fault conditions to comply with EIA/TIA-232-E.

The SN75C188 is characterized for operation from 0°C to 70°C.

H = high level, L = low level,

X = don't care

Features

- Bi-MOS Technology With TTL and CMOS Compatibility
- Meets or Exceeds the Requirements of ANSI EIA/TIA-232-E and ITU Recommendation V.28
- Very Low Quiescent Current...95 uA Typ $V_{CC+} = \pm 12 \text{ V}$
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- CMOS-and TTL-Compatible Inputs
- On-Chip Slew Rate Limited to 30 V/us max
- Flexible Supply Voltage Range
- Characterized at V_{CC+} of ± 4.5 V and ± 15 V
- Functionally Interchangeable With Texas Instruments SN75188, Motorola MC1488,

and National Semiconductor DS14C88

To view the following documents, <u>Acrobat Reader 3.x</u> is required. To download a document to your hard drive, right-click on the link and choose 'Save'.

Datasheets

Full datasheet in Acrobat PDF: <u>stls033f.pdf</u> (166 KB)
Full datasheet in Zipped PostScript: <u>stls033f.psz</u> (145 KB)

Pricing/Samples/Availability

Orderable Device	<u>Package</u>	<u>Pins</u>	Temp (°C)	<u>Status</u>	Price/unit USD (100-999)	Pack Qty	Availability / Samples
SN75C188D	<u>D</u>	14	0 TO 70	ACTIVE	1.00	50	Check stock or order
SN75C188DBLE	<u>DB</u>	14	0 TO 70	OBSOLETE			
SN75C188DBR	<u>DB</u>	14	0 TO 70	ACTIVE	0.84	2000	Check stock or order
SN75C188DR	<u>D</u>	14	0 TO 70	ACTIVE	0.87	2500	Check stock or order
SN75C188N	N	14	0 TO 70	ACTIVE	1.00	25	Check stock or order
SN75C188NS	<u>NS</u>	14	0 TO 70	ACTIVE			Check stock or order

Application Reports

- 422 AND 485 OVERVIEW AND SYSTEM CONFIGURATIONS (SLLA070 Updated: 02/15/2000)
- ANALOG APPLICATIONS JOURNAL, FEBRUARY 2000 (SLYT012A Updated: 03/23/2000)
- ANALOG APPLICATIONS JOURNAL, NOVEMBER 1999 (SLYT010A Updated: 03/23/2000)
- COMPARING BUS SOLUTIONS (SLLA067 Updated: 03/06/2000)
- ELECTROSTATIC DISCHARGE APPLICATION NOTE (SSYA008 Updated: 05/05/1999)
- INTERFACE CIRCUITS FOR TIA/EIA-232-F (SLLA037 Updated: 02/05/1999)
- JITTER ANALYSIS (SLLA075 Updated: 03/31/2000)
- SKEW DEFINITIONS (SLLA060 Updated: 08/13/1999)
- THERMAL CHARACTERISTICS OF LINEAR AND LOGIC PACKAGES USING JEDEC PCB DESIGNS (SZZA017A Updated: 09/15/1999)

Related Documents

A STATISTICAL SURVEY OF COMMON-MODE NOISE (SLLA057, 131 KB - Updated: 12/23/1999)

Table Data Updated on: 6/2/2000

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